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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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## 30V P-Channel MOSFET



**SOT-26** 

#### Pin Definition:

1. Drain

6. Drain

2. Drain

5. Drain

3. Gate

4. Source

### **Key Parameter Performance**

Parameter		Value	Unit	
$V_{DS}$		-30	٧	
R <sub>DS(on)</sub> (max)	V <sub>GS</sub> = -10V	60	mΩ	
	$V_{GS} = -4.5V$	100		
$Q_g$		9.52	nC	

### **Features**

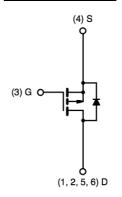
- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

### **Ordering Information**

Part No.	Package	Packing
TSM3457CX6 RFG	SOT-26	3kpcs / 7" Reel

**Note:** "G" denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

### **Block Diagram**



P-Channel MOSFET

### **Absolute Maximum Ratings** (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Voltage		$V_{GS}$	±20	V
Continuous Drain Current		I <sub>D</sub>	-5	Α
Pulsed Drain Current		I <sub>DM</sub>	-20	Α
Continuous Source Current (Diode Con	nduction) (Note 1,2)	I <sub>S</sub>	-1.7	Α
Maximum Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2.0	W
	T <sub>A</sub> =70°C		1.3	
Operating Junction Temperature		TJ	+150	°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C

#### **Thermal Performance**

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	$R_{ ext{ iny GJC}}$	30	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	R <sub>eJA</sub>	80	°C/W

## 30V P-Channel MOSFET



**Electrical Specifications** (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static (Note 3)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV <sub>DSS</sub>	-30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	$V_{GS(TH)}$	-1.0	-1.5	-3.0	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -24V, V_{GS} = 0V$	I <sub>DSS</sub>			-1.0	μΑ
On-State Drain Current	$V_{DS} = -5V, V_{GS} = -10V$	I <sub>D(ON)</sub>	-20			Α
Dunin Course On Otata Banistana	$V_{GS} = -4.5V$ , $I_{D} = -3.7A$	R <sub>DS(ON)</sub>		82	100	mΩ
Drain-Source On-State Resistance	$V_{GS} = -10V, I_D = -5A$			50	60	
Forward Transconductance	$V_{DS} = -15V, I_{D} = -5A$	g <sub>fs</sub>		10		S
Diode Forward Voltage	$I_S = -1.7A, V_{GS} = 0V$	V <sub>SD</sub>		-0.8	-1.2	V
Dynamic (Note 4,5)						
Total Gate Charge	$V_{DS} = -15V, I_{D} = -3.7A,$ $V_{GS} = -10V$	$Q_g$		9.52		
Gate-Source Charge		$Q_gs$		3.43		nC
Gate-Drain Charge		$Q_{gd}$		1.71		
Input Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	C <sub>iss</sub>		551.57		
Output Capacitance		C <sub>oss</sub>		90.96		рF
Reverse Transfer Capacitance		C <sub>rss</sub>		60.79		
Switching (Note 4,5)						
Turn-On Delay Time	$V_{DD} = -15V, \ R_L = 15\Omega, \\ I_D = -1A, \ V_{GEN} = -10V, \\ R_G = 6\Omega$	t <sub>d(on)</sub>		10.8		
Turn-On Rise Time		t <sub>r</sub>		2.33		
Turn-Off Delay Time		t <sub>d(off)</sub>		22.53		ns
Turn-Off Fall Time		t <sub>f</sub>		3.87		

#### Notes:

- 1. Pulse width limited by the Maximum junction temperature
- 2. Surface Mounted on FR4 Board, t ≤ 5 sec.
- 3. pulse test: PW  $\leq$  300 $\mu$ S, duty cycle  $\leq$  2%
- 4. For DESIGN AID ONLY, not subject to production testing.
- 5. Switching time is essentially independent of operating temperature.

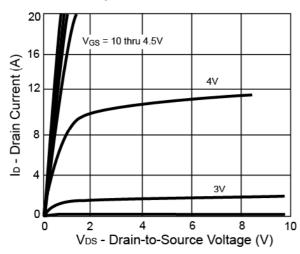


## 30V P-Channel MOSFET

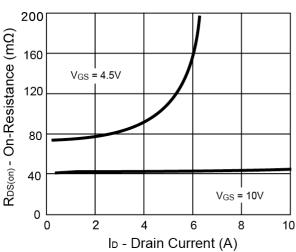


#### **Electrical Characteristics Curves**

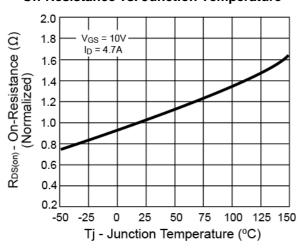
#### **Output Characteristics**



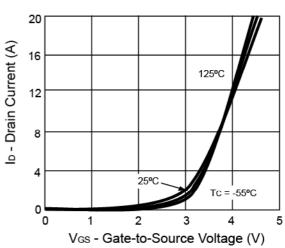
#### **On-Resistance vs. Drain Current**



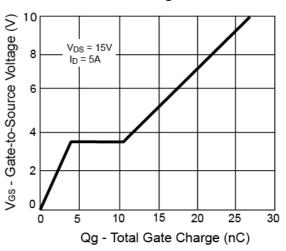
**On-Resistance vs. Junction Temperature** 



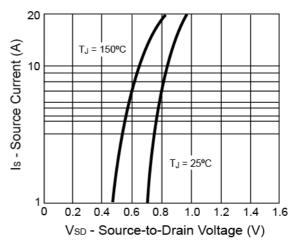
**Transfer Characteristics** 



**Gate Charge** 



Source-Drain Diode Forward Voltage



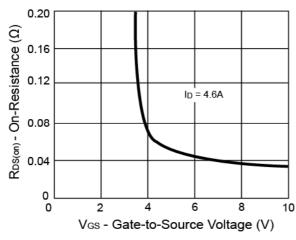


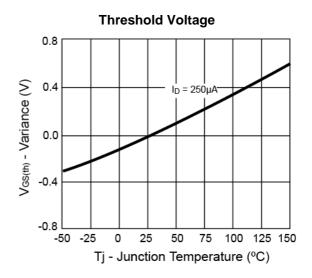
## 30V P-Channel MOSFET



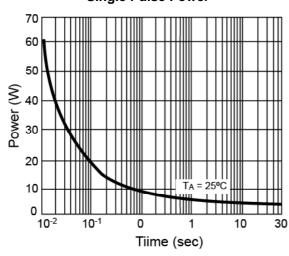
#### **Electrical Characteristics Curves**

### On-Resistance vs. Gate-Source Voltage

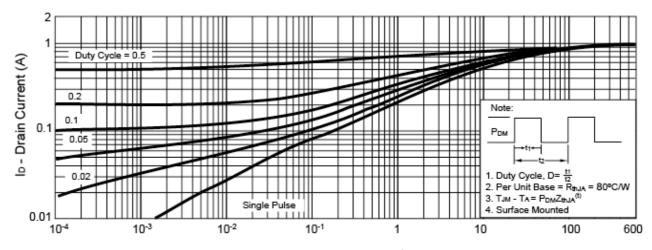




#### **Single Pulse Power**



### Normalized Thermal Transient Impedance, Junction-to-Ambient

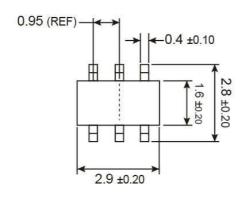


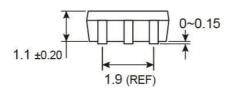
Square Wave Pulse Duration (sec)

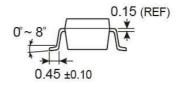




# **SOT-26 Mechanical Drawing**







Unit: Millimeters

## **Marking Diagram**



**57** = Device Code

Y = Year Code

**M** = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr S =May T =Jun U =Jul V =Aug

W =Sep X =Oct Y =Nov Z =Dec

L = Lot Code



# TSM3457 30V P-Channel MOSFET

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